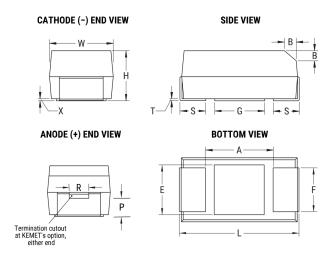


T495D337K010ATA125

T495 Auto, Tantalum, MnO2 Tantalum, 330 uF, 10%, 10 VDC, SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200, 125 mOhms, 7343, Height Max = 3.1mm



Click here for the 3D model.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
Α	3.6mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Information	
Series	T495 Auto
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR, Auto, AEC- Q200
Features	Low ESR, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Component Weight	446.84 mg

Specifications	
Capacitance	330 uF
Capacitance Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	10% 120Hz 25C
Failure Rate	N/A
Resistance	125 mOhms (100kHz 25C)
Ripple Current	1095 mA (rms, 100kHz 25C), 985.5 mA (rms, 85C), 438 mA (rms, 125C)
Leakage Current	33 uA (5min 25°C)

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